

- **2.5-V Virtual Ground for 5-V/GND Analog Systems**
- **High Output-Current Capability Sink or Source . . . 20 mA Typ**
- **Micropower Operation . . . 170  $\mu$ A Typ**
- **Excellent Regulation Characteristics**
  - Output Regulation
    - 45  $\mu$ V Typ at  $I_O = 0$  to –10 mA
    - +15  $\mu$ V Typ at  $I_O = 0$  to +10 mA
  - Input Regulation = 1.5  $\mu$ V/V Typ
- **Low-Impedance Output . . . 0.0075  $\Omega$  Typ**
- **Macromodel Included**

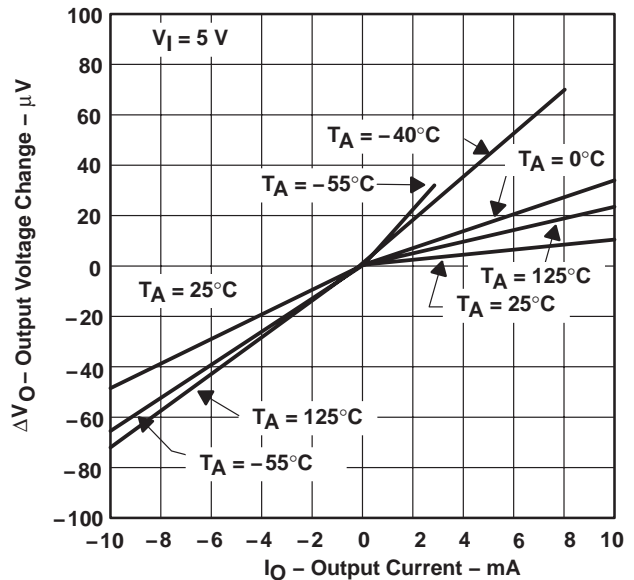
## description

In signal-conditioning applications using a single power source, a reference voltage is required for termination of all signal grounds. To accomplish this, engineers have typically used solutions consisting of resistors, capacitors, operational amplifiers, and voltage references. Texas Instruments has eliminated all of those components with one easy-to-use 3-terminal device. That device is the TLE2425 precision virtual ground.

Use of the TLE2425 over other typical circuit solutions gives the designer increased dynamic signal range, improved signal-to-noise ratio, lower distortion, improved signal accuracy, and easier interfacing to ADCs and DACs. These benefits are the result of combining a precision micropower voltage reference and a high-performance precision operational amplifier in a single silicon chip. It is the precision and performance of these two circuit functions together that yield such dramatic system-level performance.

The TLE2425 improves input regulation as well as output regulation and, in addition, reduces output impedance and power dissipation in a majority of virtual-ground-generation circuits. Both input regulation and load regulation exceed 12 bits of accuracy on a single 5-V system. Signal-conditioning front ends of data acquisition systems that push 12 bits and beyond can use the TLE2425 to eliminate a major source of system error.

## OUTPUT REGULATION



### AVAILABLE OPTIONS

T <sub>A</sub>	SMALL OUTLINE (D)	PLASTIC TO-226AA (LP)
0°C to 70°C	TLE2425CD	TLE2425CD
–40°C to 85°C	TLE2425ID	TLE2425ID
–55°C to 125°C	TLE2425MD	—

† The D package is available taped and reeled. Add R suffix to the device type (e.g., TLE2425CDR).



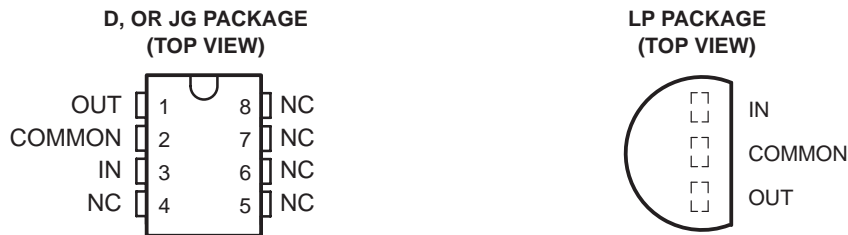
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**PRODUCTION DATA** information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



# TLE2425 PRECISION VIRTUAL GROUND

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NC – No internal connection

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Continuous input voltage, $V_I$	40 V
Output current, $I_O$	$\pm 80$ mA
Duration of short-circuit current at (or below) 25°C (see Note 1)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ :	
C-suffix	0°C to 70°C
I-suffix	-40°C to 85°C
M-suffix	-55°C to 125°C
Storage temperature range, $T_{stg}$	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG or LP package	300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$	DERATING FACTOR	$T_A = 70^\circ\text{C}$	$T_A = 85^\circ\text{C}$	$T_A = 125^\circ\text{C}$
	POWER RATING	ABOVE $T_A = 25^\circ\text{C}$	POWER RATING	POWER RATING	POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
LP	775 mW	6.2 mW/°C	496 mW	403 mW	155 mW

## recommended operating conditions

	C-SUFFIX		I-SUFFIX		M-SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	
Input voltage, $V_I$	4	40	4	40	4	40	V
Operating free-air temperature, $T_A$	0	70	-40	85	-55	125	°C



**electrical characteristics at specified free-air temperature,  $V_I = 5\text{ V}$ ,  $I_O = 0$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLE2425C			UNIT
			MIN	TYP	MAX	
Output voltage		25°C	2.48	2.5	2.52	V
		Full range	2.47		2.53	
Temperature coefficient of output voltage		25°C		20		ppm/°C
Bias current	$I_O = 0$	25°C		170	250	μA
		Full range			250	
Input voltage regulation	$V_I = 4.5\text{ V to }5.5\text{ V}$	25°C		1.5	20	μV
		Full range			25	
	$V_I = 4\text{ V to }40\text{ V}$	25°C		1.5	20	μV/V
		Full range			25	
Ripple rejection	$f = 120\text{ Hz}$ , $\Delta V_I(\text{PP}) = 1\text{ V}$	25°C		80		dB
Output voltage regulation (source current)‡	$I_O = 0\text{ to }-10\text{ mA}$	25°C	-160	-45	160	μV
	Full range		-250		250	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }10\text{ mA}$	25°C	-160	15	160	μV
		Full range			250	
	$I_O = 0\text{ to }20\text{ mA}$	25°C	-235	65	235	
Long-term drift of output voltage	$\Delta t = 1000\text{ h}$ , Noncumulative	25°C		15		ppm
Output impedance		25°C		7.5	22.5	mΩ
Short-circuit output current (sink current)	$V_O = 5\text{ V}$	25°C	30	55		mA
Short-circuit output current (source current)	$V_O = 0$		-30	-50		
Output noise voltage, rms	$f = 10\text{ Hz to }10\text{ kHz}$	25°C		100		μV
Output voltage response to output current step	$V_O\text{ to }0.1\%$ , $I_O = \pm 10\text{ mA}$	25°C	$C_L = 0$		110	μs
			$C_L = 100\text{ pF}$		115	
	$V_O\text{ to }0.01\%$ , $I_O = \pm 10\text{ mA}$	$C_L = 0$		180		
		$C_L = 100\text{ pF}$		180		
Output voltage response to input voltage step	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C		12	μs	
	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.01\%$			30		
Output voltage turn-on response	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C		125	μs	
	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.01\%$			210		

† Full range is 0°C to 70°C.

‡ The listed values are not production tested.

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electrical characteristics at specified free-air temperature,  $V_I = 5\text{ V}$ ,  $I_O = 0$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A$ †	TLE2425I			UNIT
			MIN	TYP	MAX	
Output voltage		25°C	2.48	2.5	2.52	V
		Full range	2.47		2.53	
Temperature coefficient of output voltage		25°C	20			ppm/°C
Bias current	$I_O = 0$	25°C	170	250		μA
		Full range		250		
Input voltage regulation	$V_I = 4.5\text{ V to }5.5\text{ V}$	25°C	1.5	20		μV
		Full range		75		
	$V_I = 4\text{ V to }40\text{ V}$	25°C	1.5	20		μV/V
		Full range		75		
Ripple rejection	$f = 120\text{ Hz}$ , $\Delta V_I(\text{PP}) = 1\text{ V}$	25°C	80			dB
Output voltage regulation (source current)‡	$I_O = 0\text{ to }-10\text{ mA}$	25°C	-160	-45	160	μV
	Full range		-250		250	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }-20\text{ mA}$	25°C	-450	-150	450	μV
	$I_O = 0\text{ to }8\text{ mA}$	25°C	-160	15	160	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }8\text{ mA}$	25°C	-160	15	160	μV
	Full range		-250		250	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }20\text{ mA}$	25°C	-235	65	235	μV
	Full range		-235		235	
Long-term drift of output voltage	$\Delta t = 1000\text{ h}$ , Noncumulative	25°C	15			ppm
Output impedance		25°C	7.5	22.5		mΩ
Short-circuit output current (sink current)	$V_O = 5\text{ V}$	25°C	30	55		mA
Short-circuit output current (source current)	$V_O = 0$		-30	-50		
Output noise voltage, rms	$f = 10\text{ Hz to }10\text{ kHz}$	25°C	100			μV
Output voltage response to output current step	$V_O\text{ to }0.1\%$ , $I_O = \pm 10\text{ mA}$	$C_L = 0$	110			μs
		$C_L = 100\text{ pF}$	115			
	$V_O\text{ to }0.01\%$ , $I_O = \pm 10\text{ mA}$	$C_L = 0$	180			
		$C_L = 100\text{ pF}$	180			
Output voltage response to input voltage step	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C	12			μs
	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.01\%$		30			
Output voltage turn-on response	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C	125			μs
	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.01\%$		210			

† Full range is -40°C to 85°C.

‡ The listed values are not production tested.



**electrical characteristics at specified free-air temperature,  $V_I = 5\text{ V}$ ,  $I_O = 0$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLE2425M			UNIT
			MIN	TYP	MAX	
Output voltage		25°C	2.48	2.5	2.52	V
		Full range	2.47		2.53	
Temperature coefficient of output voltage		25°C	20			ppm/°C
Bias current	$I_O = 0$	25°C	170	250		μA
		Full range		250		
Input voltage regulation	$V_I = 4.5\text{ V to }5.5\text{ V}$	25°C	1.5	20		μV
		Full range		100		
	$V_I = 4.5\text{ V to }40\text{ V}$	25°C	1.5	20		μV/V
		Full range		100		
Ripple rejection	$f = 120\text{ Hz}$ , $\Delta V_I(\text{PP}) = 1\text{ V}$	25°C	80			dB
Output voltage regulation (source current)‡	$I_O = 0\text{ to }-10\text{ mA}$	25°C	-160	-45	160	μV
	Full range		-250		250	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }-20\text{ mA}$	25°C	-450	-150	450	μV
	$I_O = 0\text{ to }3\text{ mA}$	25°C	-160	15	160	
Output voltage regulation (sink current)‡	$I_O = 0\text{ to }20\text{ mA}$	25°C	-235	65	235	μV
	Full range		-250		250	
Long-term drift of output voltage	$\Delta t = 1000\text{ h}$ , Noncumulative	25°C	15			ppm
Output impedance		25°C	7.5	22.5		mΩ
Short-circuit output current (sink current)	$V_O = 5\text{ V}$	25°C	30	55		mA
Short-circuit output current (source current)	$V_O = 0$		-30	-50		
Output noise voltage, rms	$f = 10\text{ Hz to }10\text{ kHz}$	25°C	100			μV
Output voltage response to output current step	$V_O\text{ to }0.1\%$ , $I_O = \pm 10\text{ mA}$	25°C	$C_L = 0$	110		μs
			$C_L = 100\text{ pF}$	115		
	$V_O\text{ to }0.01\%$ , $I_O = \pm 10\text{ mA}$	$C_L = 0$	180			
		$C_L = 100\text{ pF}$	180			
Output voltage response to input voltage step	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C	12			μs
	$V_I = 4.5\text{ to }5.5\text{ V}$ , $V_O\text{ to }0.01\%$		30			
Output voltage turn-on response	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.1\%$	25°C	125			μs
	$V_I = 0\text{ to }5\text{ V}$ , $V_O\text{ to }0.01\%$		210			

† Full range is -55°C to 125°C.

‡ The listed values are not production tested.

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## TYPICAL CHARACTERISTICS

Table Of Graphs

		FIGURE
Output voltage	Distribution	1
	vs Free-air temperature	2
Output voltage hysteresis	vs Free-air temperature	3
Input bias current	vs Input voltage	4
	vs Free-air temperature	5
Input voltage regulation		6
Ripple rejection	vs Frequency	7
Output voltage regulation		8
Output impedance	vs Frequency	9
Short-circuit output current	vs Free-air temperature	10
Spectral noise voltage density	vs Frequency	11
Wide-band noise voltage	vs Frequency	12
Output voltage change with current step	vs Time	13
Output voltage change with voltage step	vs Time	14
Output voltage power-up response	vs Time	15
Output current	vs Load capacitance	16



TYPICAL CHARACTERISTICS†

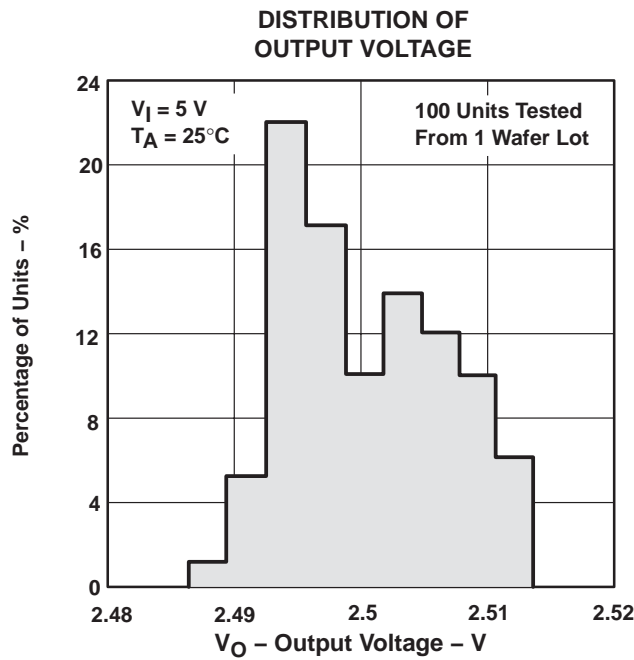


Figure 1

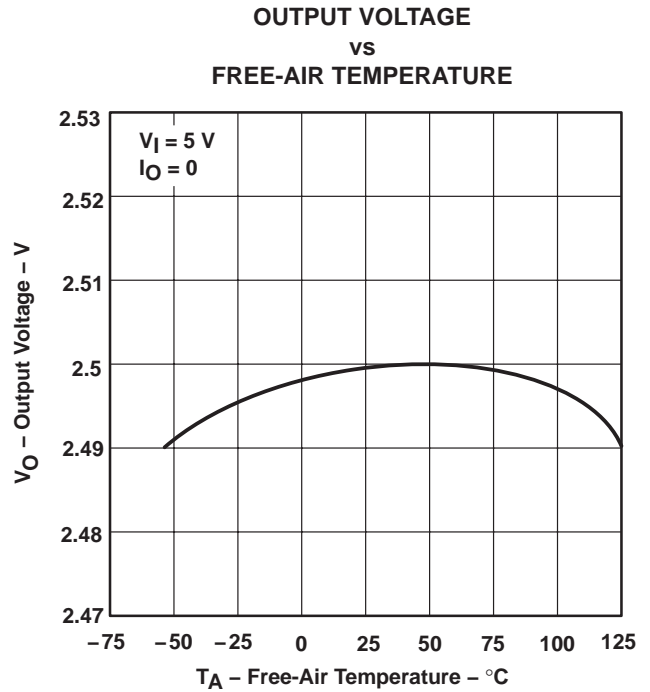


Figure 2

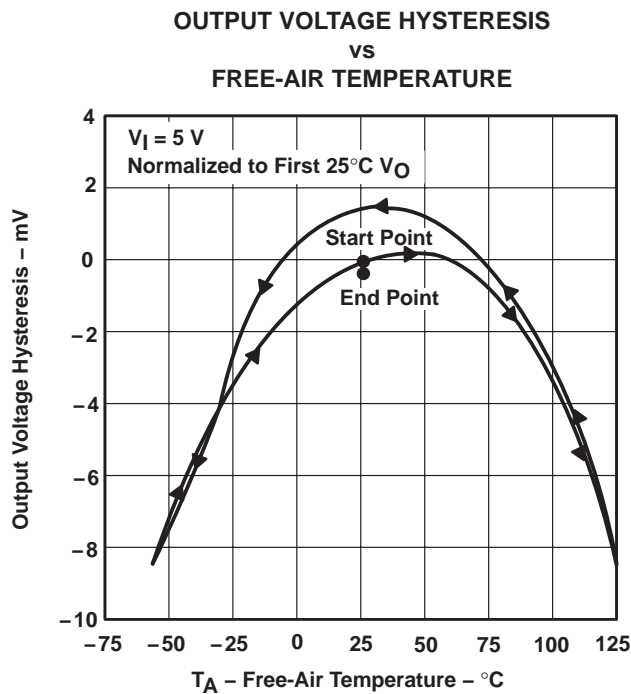


Figure 3

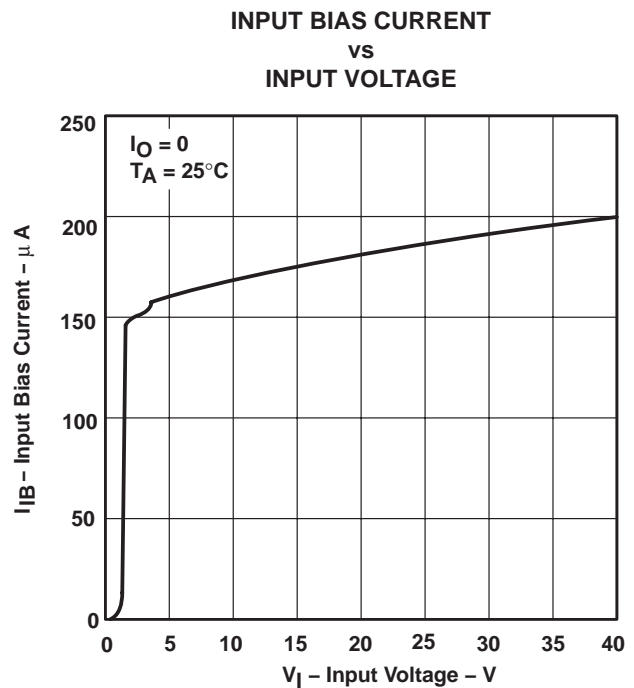


Figure 4

† Data at high and low temperatures are applicable within rated operating free-air temperature ranges of the various devices.

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## TYPICAL CHARACTERISTICS†

**INPUT BIAS CURRENT  
vs  
FREE-AIR TEMPERATURE**

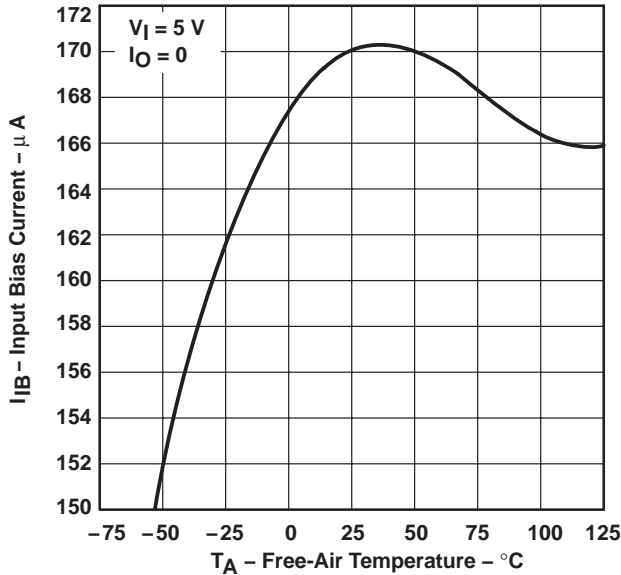


Figure 5

**INPUT VOLTAGE REGULATION**

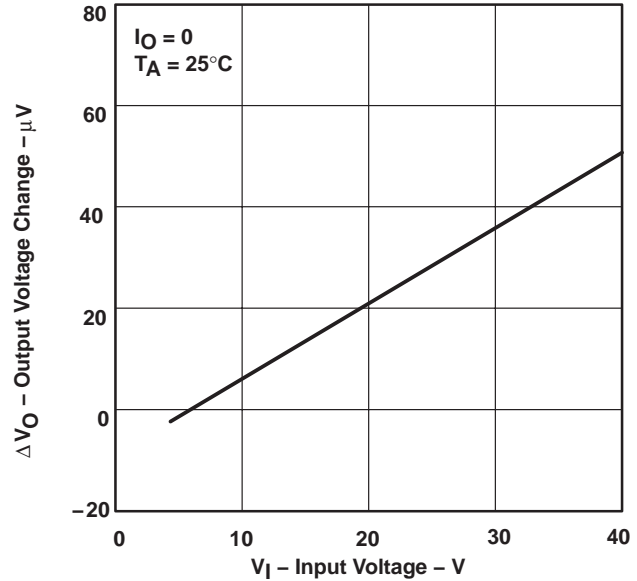


Figure 6

**RIPPLE REJECTION  
vs  
FREQUENCY**

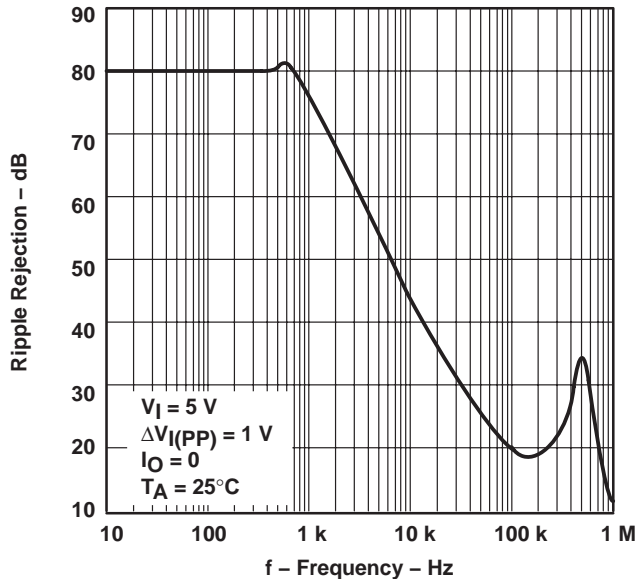


Figure 7

**OUTPUT VOLTAGE REGULATION**

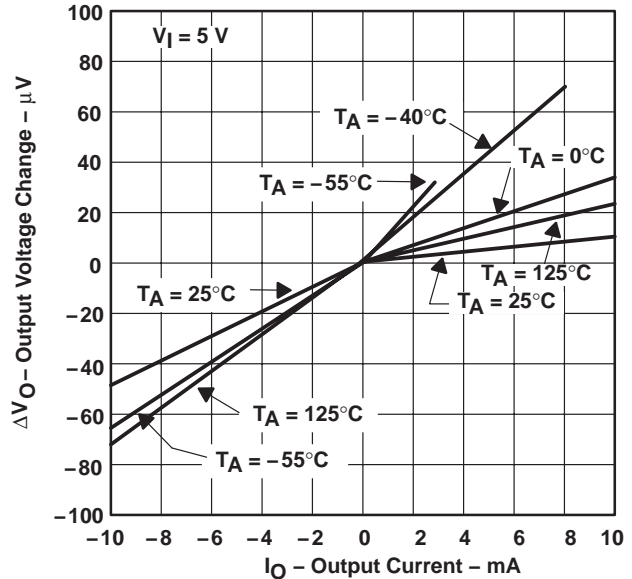


Figure 8

† Data at high and low temperatures are applicable within rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

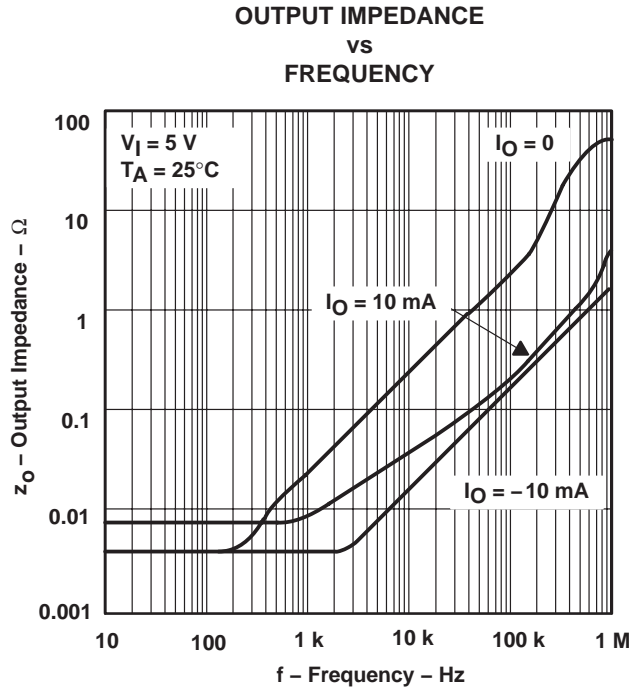


Figure 9

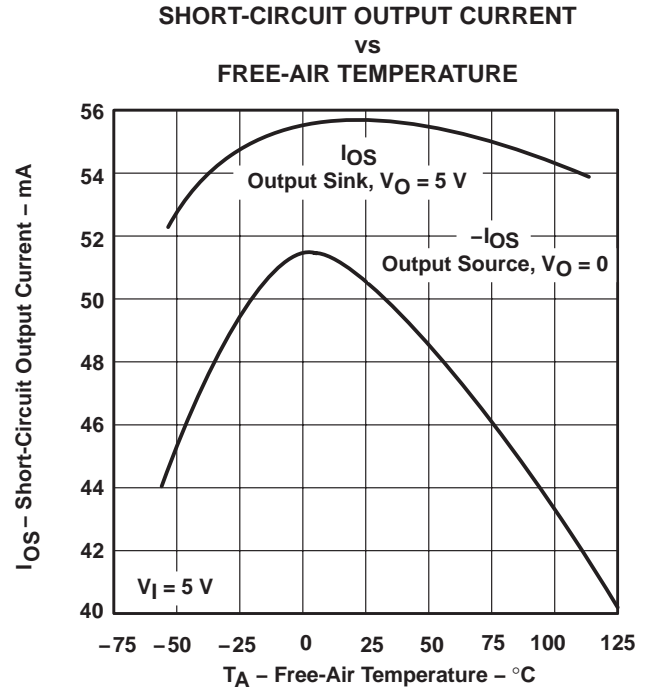


Figure 10

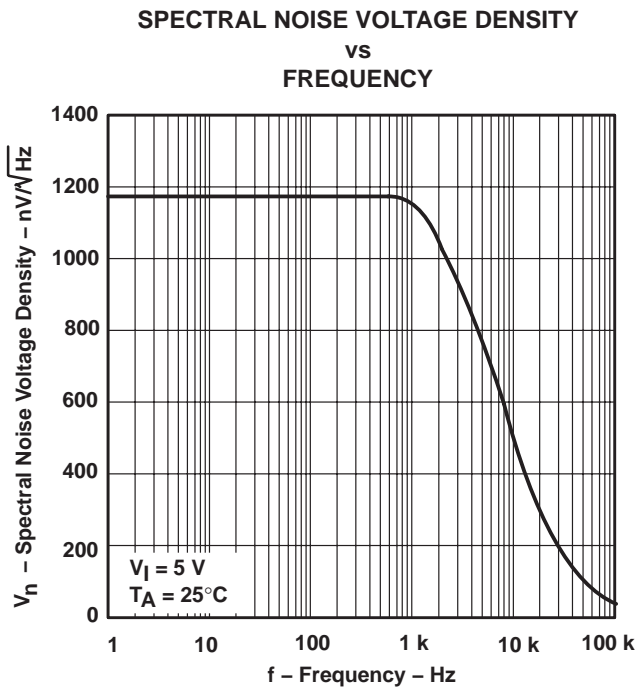


Figure 11

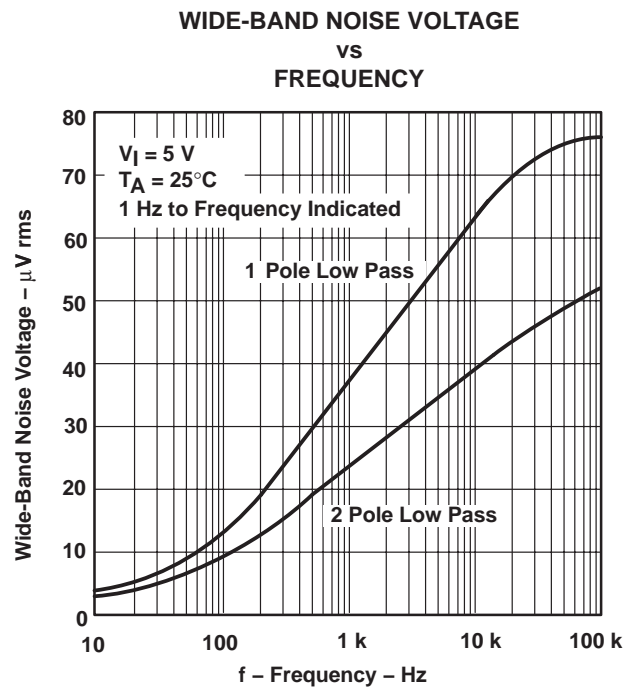
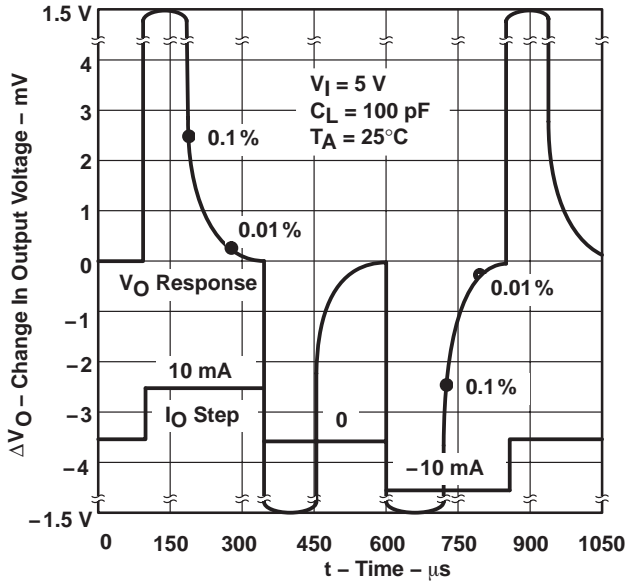


Figure 12

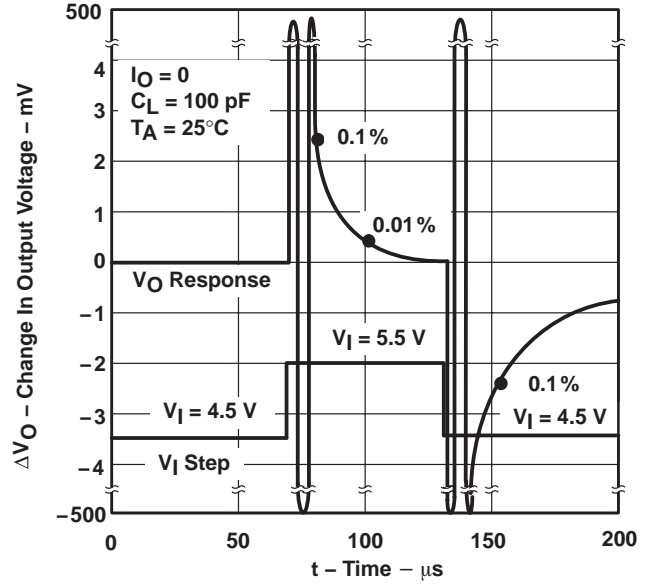
**TYPICAL CHARACTERISTICS**

**OUTPUT VOLTAGE RESPONSE TO OUTPUT CURRENT STEP VS TIME**



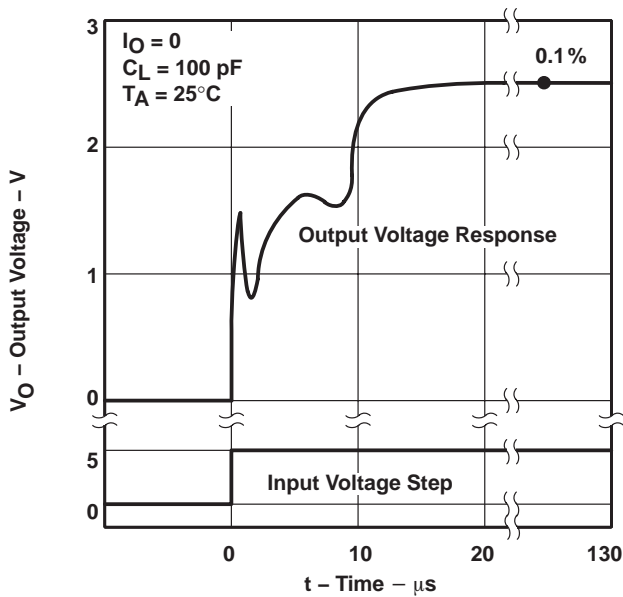
**Figure 13**

**OUTPUT VOLTAGE RESPONSE TO INPUT VOLTAGE STEP VS TIME**



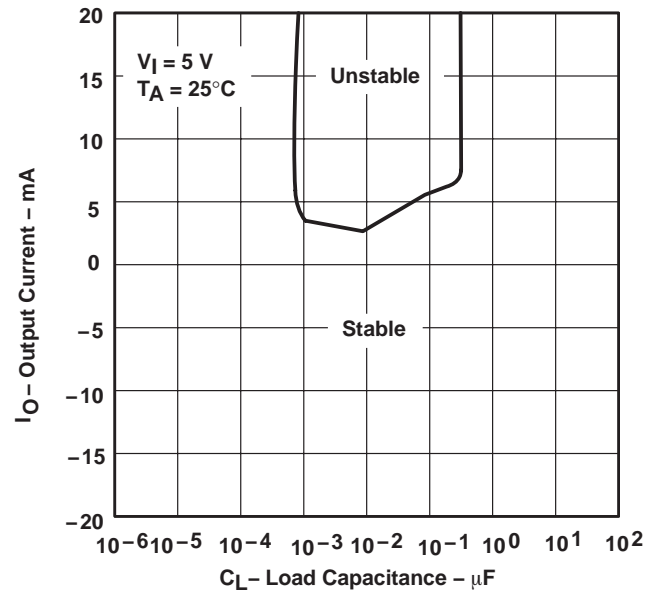
**Figure 14**

**OUTPUT VOLTAGE POWER-UP RESPONSE VS TIME**



**Figure 15**

**STABILITY RANGE OUTPUT CURRENT VS LOAD CAPACITANCE**



**Figure 16**

macromodel information

```
* TLE2425 OPERATIONAL AMPLIFIER "MACROMODEL" SUBCIRCUIT
* CREATED USING PARTS RELEASE 4.03 ON 08/21/90 AT 13:51
* REV (N/A) SUPPLY VOLTAGE: 5 V
* CONNECTIONS: INPUT
*
*           | COMMON
*           | OUTPUT
*
.SUBCKT TLE2425 3 4 5
*
```

```
* OPAMP SECTION
C1 11 12 21.66E-12
C2 6 7 30.00E-12
C3 87 0 10.64E-9
CPSR 85 86 15.9E-9
DCM+ 81 82 DX
DCM- 83 81 DX
DC 5 53 DX
DE 54 5 DX
DLN 92 90 DX
DLP 90 91 DX
DP 4 3 DX
ECMR 84 99 (2,99) 1
EGND 99 0 POLY(2) (3,0) (4,0) 0 .5 .5
EPSR 85 0 POLY(1) (3,4) -16.22E-6 3.24E-6
ENSE 89 2 POLY(1) (88,0) 120E-6 1
FB 7 99 POLY(6) VB VC VE VLP VLN VPSR 0 74.8E6 -10E6 10E6 10E6
+ -10E6 74E6
GA 6 0 11 12 320.4E-6
GCM 0 6 10 99 1.013E-9
GPSR 85 86 (85,86) 100E-6
GRC1 4 11 (4,11) 3.204E-4
GRC2 4 12 (4,12) 3.204E-4
GRE1 13 10 (13,10) 1.038E-3
GRE2 14 10 (14,10) 1.038E-3
HLIM 90 0 VLIM 1K
HCMR 80 1 POLY(2) VCM+ VCM- 0 1E2 1E2
IRP 3 4 146E-6
IEE 3 10 DC 24.05E-6
IIO 2 0 .2E-9
I1 88 0 1E-21
Q1 11 89 13 QX
Q2 12 80 14 QX
R2 6 9 100.0E3
RCM 84 81 1K
REE 10 99 8.316E6
RN1 87 0 2.55E8
RN2 87 88 11.67E3
```

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## macromodel information (continued)

```
RO1      8  5  63
RO2      7 99  62
VCM+    82 99  1.0
VCM-    83 99 -2.3
VB       9  0  DC  0
VC       3 53  DC  1.400
VE      54  4  DC  1.400
VLIM     7  8  DC  0
VLP     91  0  DC  30
VLN      0 92  DC  30
VPSR     0 86  DC  0
RFB      5  2  1K
RIN     30  1  1K
RCOM    34  4  .1
*REGULATOR SECTION
RG1     30  0  20MEG
RG2     30 31  .2
RG3     31 35  400K
RG4     35 34  411K
RG5     31 36  25MEG
HREG    31 32  POLY(2)  VPSET VNSET  0  1E2 1E2
VREG    32 33  DC  0V
EREG    33 34  POLY(1)  (36,34)  1.23  1
VADJ    36 34  1.27V
HPSET   37  0  VREG  1.030E3
VPSET   38  0  DC  20V
HNSET   39  0  VREG  6.11E5
VNSET   40  0  DC -20V
DSUB    4  34  DX
DPOS    37 38  DX
DNNEG   40 39  DX
.MODEL DX D(IS=800.0E-18)
.MODEL QX PNP(IS=800.0E-18 BF=480)
.ENDS
```

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TLE2425CD</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	2425C
<a href="#">TLE2425CDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2425C
<a href="#">TLE2425CLP</a>	Active	Production	TO-92 (LP)   3	1000   BULK	Yes	SN	N/A for Pkg Type	-	2425C
<a href="#">TLE2425CPS</a>	Active	Production	SO (PS)   8	80   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	Q2425
<a href="#">TLE2425CPSR</a>	Active	Production	SO (PS)   8	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	Q2425
<a href="#">TLE2425ID</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	2425I
<a href="#">TLE2425IDR</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2425I
<a href="#">TLE2425ILP</a>	Active	Production	TO-92 (LP)   3	1000   BULK	Yes	SN	N/A for Pkg Type	-	2425I
<a href="#">TLE2425MD</a>	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2425M
<a href="#">TLE2425MDRG4</a>	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2425M

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2425CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2425CPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TLE2425IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2425CDR	SOIC	D	8	2500	350.0	350.0	43.0
TLE2425CPSR	SO	PS	8	2000	356.0	356.0	35.0
TLE2425IDR	SOIC	D	8	2500	350.0	350.0	43.0



**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLE2425CD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2425CPS	PS	SOP	8	80	530	10.5	4000	4.1
TLE2425ID	D	SOIC	8	75	505.46	6.76	3810	4
TLE2425IDG4	D	SOIC	8	75	505.46	6.76	3810	4
TLE2425MD	D	SOIC	8	75	505.46	6.76	3810	4



D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed  $.006$  [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

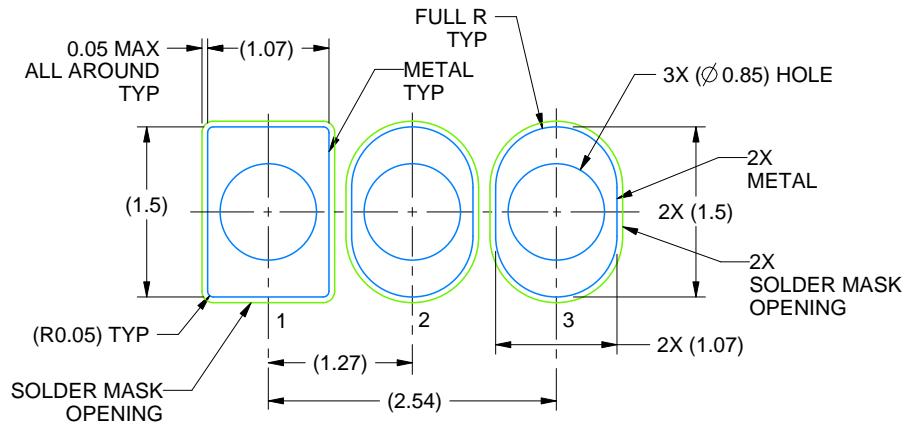


# EXAMPLE BOARD LAYOUT

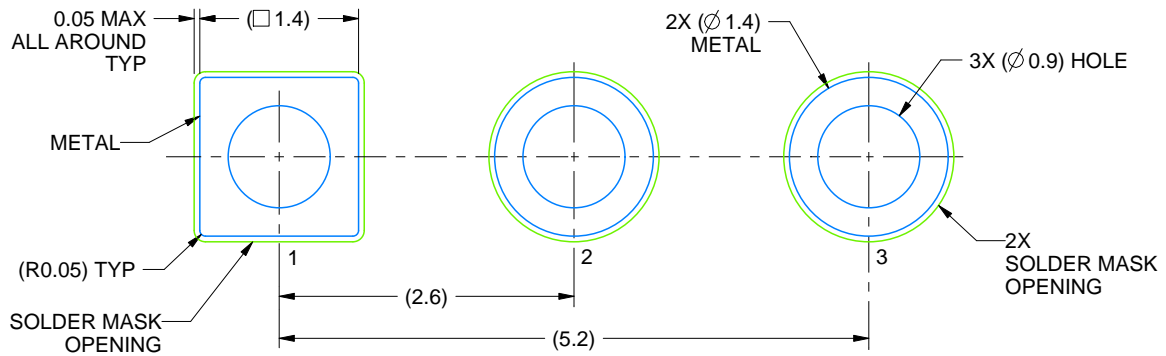
LP0003A

TO-92 - 5.34 mm max height

TO-92



LAND PATTERN EXAMPLE  
STRAIGHT LEAD OPTION  
NON-SOLDER MASK DEFINED  
SCALE:15X



LAND PATTERN EXAMPLE  
FORMED LEAD OPTION  
NON-SOLDER MASK DEFINED  
SCALE:15X

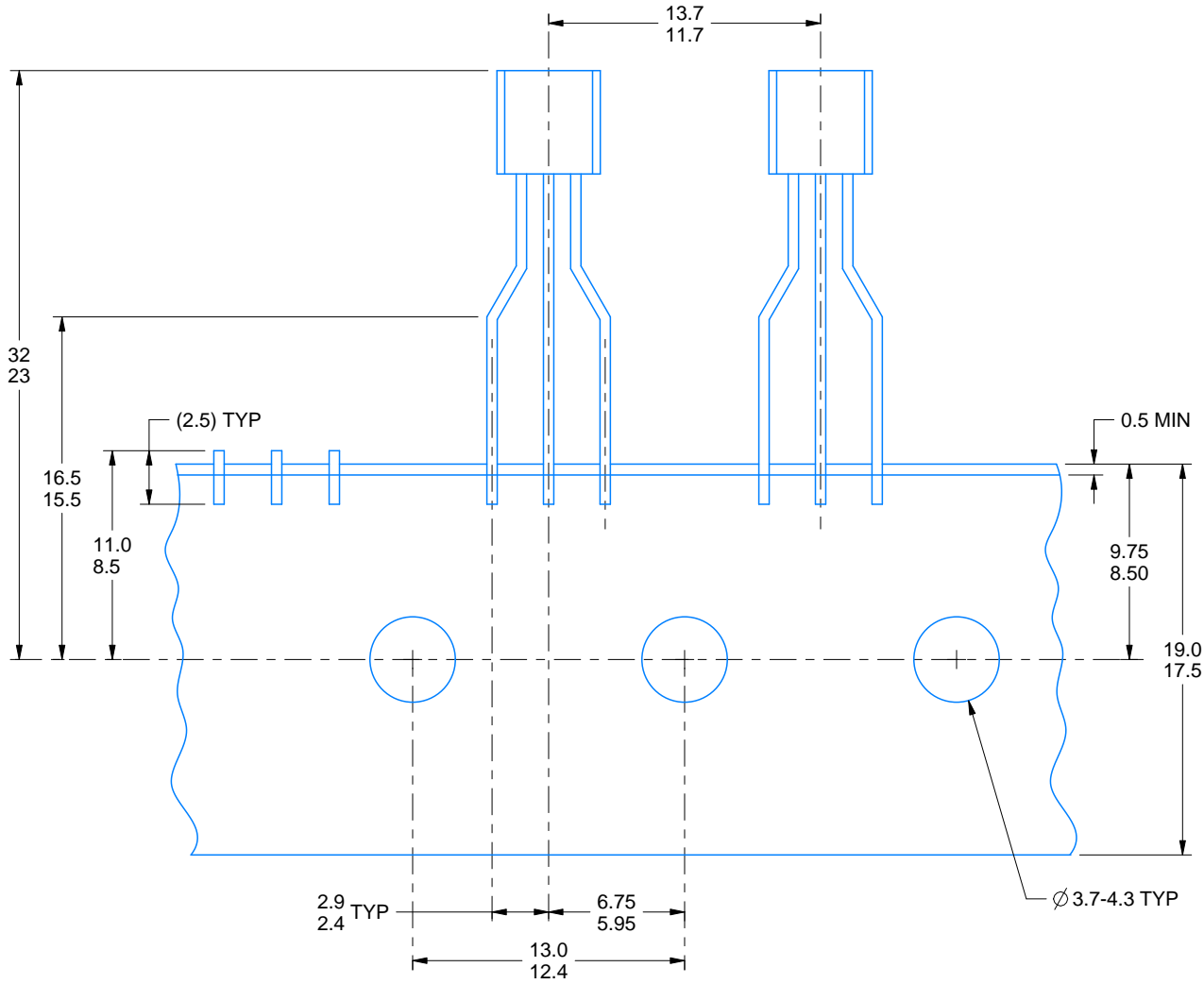
4215214/C 04/2025

# TAPE SPECIFICATIONS

LP0003A

TO-92 - 5.34 mm max height

TO-92



FOR FORMED LEAD OPTION PACKAGE

4215214/C 04/2025



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